Switch-mode Schottky Power Rectifier

MBRF2060CTG

The Switch-mode Power Rectifier employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for use as rectifiers in very low-voltage, high-frequency switching power supplies, free wheeling diodes and polarity protection diodes.

Features

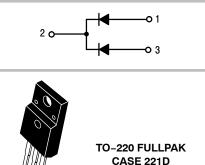
- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
- Matched Dual Die Construction
- High Junction Temperature Capability
- High dv/dt Capability
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Electrically Isolated. No Isolation Hardware Required.
- These Devices are Pb-Free and are RoHS Compliant
- Mechanical Characteristics:
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



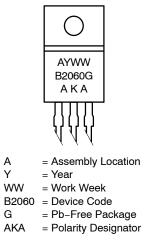
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MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping
MBRF2060CTG	TO-220FP (Pb-Free)	50 Units/Rail

MBRF2060CTG

MAXIMUM RATINGS (Per Leg)

Rating		Symbol	Value	Unit V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} 60 V _{RWM} V _R		
Average Rectified Forward Current (Rated V_R), $T_C = 133^{\circ}C$	Total Device	I _{F(AV)}	10 20	A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz), $T_C = 133^{\circ}C$		I _{FRM}	20	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	150	A
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)		I _{RRM}	0.5	Α
Operating Junction and Storage Temperature Range (Note 1)		T _J , T _{stg}	– 65 to +175	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10000	V/μs
RMS Isolation Voltage (t = 0.3 second, R.H. \leq 30%, T_A = 25°C) (Note 2)	Per Figure 3	V _{iso1}	4500	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Per Leg)

Rating		Value	Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	4.0	°C/W
Lead Temperature for Soldering Purposes: 1/8 in from Case for 5 Seconds	ΤL	260	°C

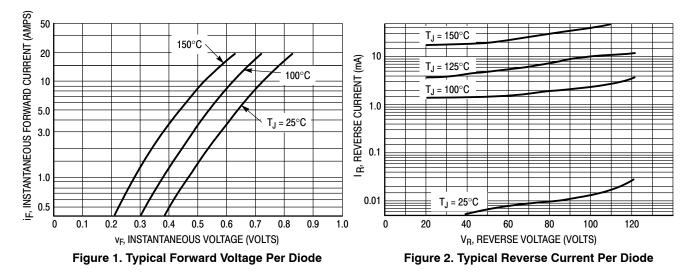
ELECTRICAL CHARACTERISTICS (Per Leg)

Characteristic	Symbol	Max	Unit
$\label{eq:maximum lnstantaneous Forward Voltage (Note 3)} \\ \begin{array}{l} (i_F = 10 \ \mbox{Amp}, \ T_C = 25^\circ C) \\ (i_F = 10 \ \mbox{Amp}, \ T_C = 125^\circ C) \\ (i_F = 20 \ \mbox{Amp}, \ T_C = 25^\circ C) \\ (i_F = 20 \ \mbox{Amp}, \ T_C = 125^\circ C) \end{array}$	VF	0.85 0.75 0.95 0.85	V
Maximum Instantaneous Reverse Current (Note 3) (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	İR	0.15 150	mA

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

2. Proper strike and creepage distance must be provided.

3. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%



MBRF2060CTG

TEST CONDITION FOR ISOLATION TEST*

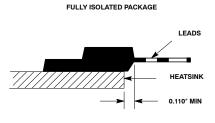
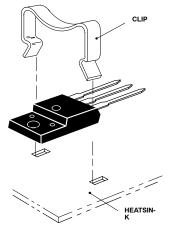


Figure 3. Mounting Position

*Measurement made between leads and heatsink with all leads shorted together.

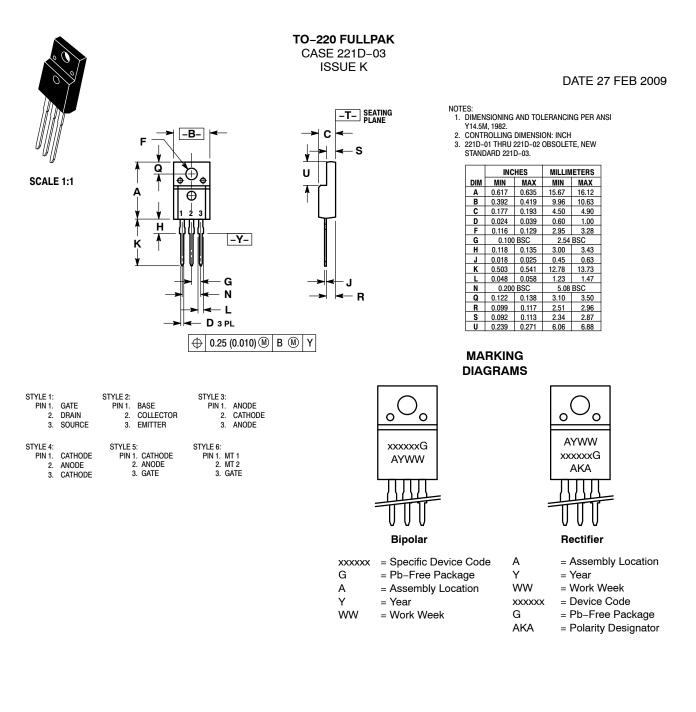
MOUNTING INFORMATION



Clip-Mounted

Figure 4. Typical Mounting Technique

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 DESCRIPTION:
 TO-220 FULLPAK
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